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on Semiconductor® FDD86567-F085

N-Channel PowerTrench[®] MOSFET 60 V, 100 A, 3.2 m Ω

Features

- Typical $R_{DS(on)}$ = 2.6 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 63 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	100	•	
	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	115	mJ	
P _D	Power Dissipation		227	W	
	Derate Above 25°C		1.52	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.66	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, $L = 40\mu$ H, $I_{AS} = 76$ A, $V_{DD} = 60$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

ROHS

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86567	FDD86567-F085	D-PAK(TO-252)	13"	16mm	2500units

т

G

S

EDD86567-F085 N-Channel PowerTrench[®] MOSFET

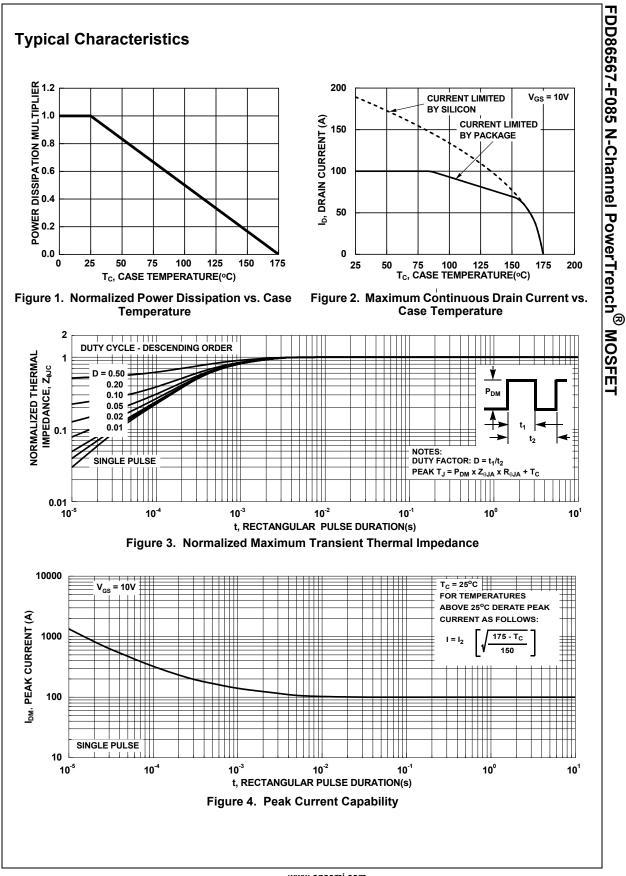
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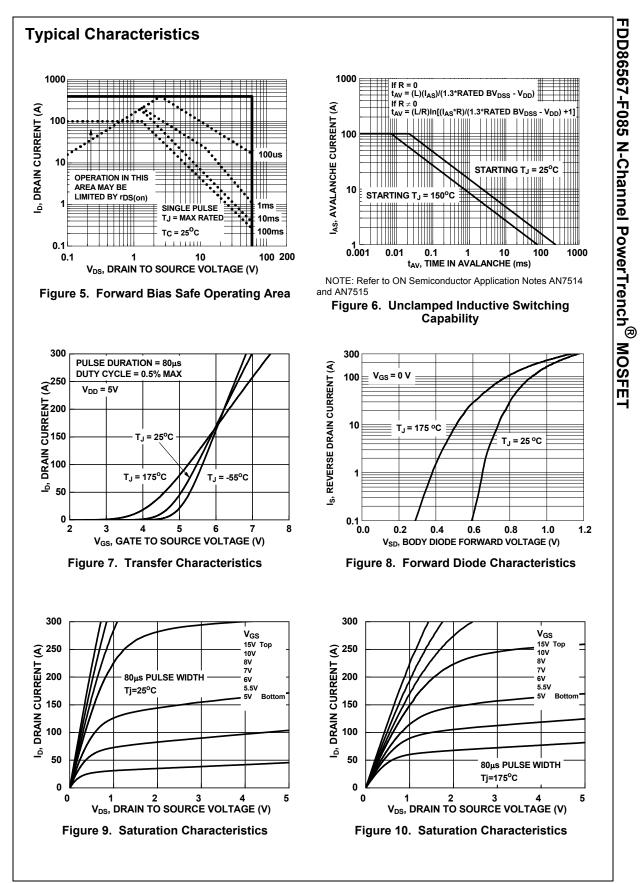
D-PAK

(TO-252)

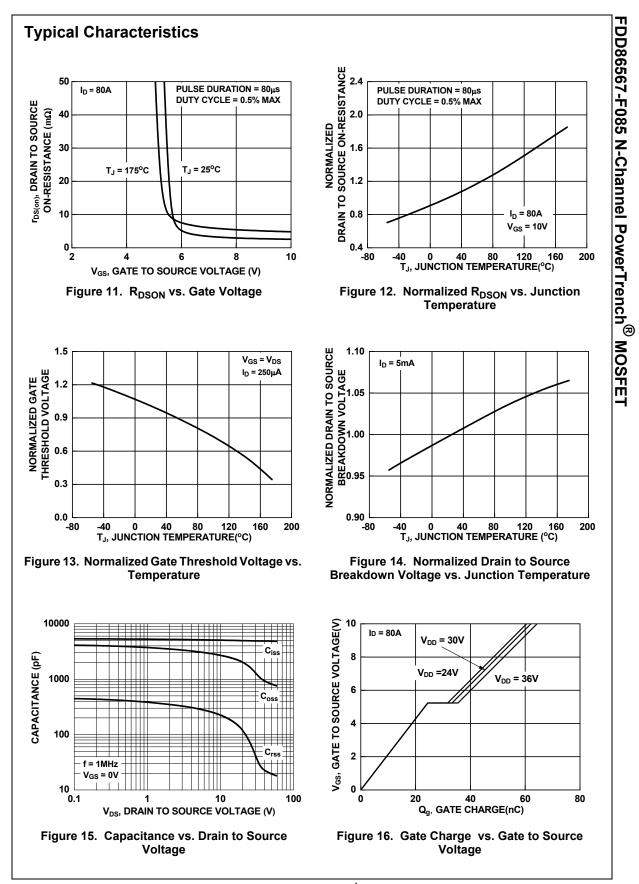
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		60	-	-	V
	rain to Source Lookage Current	V _{DS} =60V,	T _J = 25°C	-	-	1	μA
IDSS	Drain-to-Source Leakage Current		T _J = 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2	2.9	4	V
		I _D = 80A, T	$T_J = 25^{\circ}C$	-	2.6	3.2	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	T _J = 175 ^o C (Note 4)	-	4.9	6.0	mΩ
Dynami	ic Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	4950	-	pF
C _{oss}	Output Capacitance			-	1300	-	pF
C _{rss}	Reverse Transfer Capacitance			-	45	-	pF
R _g	Gate Resistance	V _{GS} = 0.5V, f = 1MHz		-	2.3	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 48V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$		-	63	82	nC
Q _{g(th)}	Threshold Gate Charge			-	9.1	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	24	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	10	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time	V _{DD} = 30V, I _D = 80A, V _{GS} = 10V, R _{GEN} = 6Ω		-	-	105	ns
t _{d(on)}	Turn-On Delay			-	24	-	ns
t _r	Rise Time			-	45	-	ns
t _{d(off)}	Turn-Off Delay			-	32	-	ns
t _f	Fall Time			-	13	-	ns
t _{off}	Turn-Off Time			-	-	59	ns
Drain-S	ource Diode Characteristics						
V	Source to Drain Diade Valtage	I _{SD} = 80A, V _{GS} = 0V I _{SD} = 40A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage			-	-	1.2	V
t _{rr}	Reverse-Recovery Time	V _{DD} = 48V, I _F = 80A, dI _{SD} /dt = 100A/μs		-	68	89	ns
	Reverse-Recovery Charge			-	76	114	nC



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